Schottky Rectifier, 5.5 A

- · Low forward voltage drop
- Guard ring for enhanced ruggedness and long RoHS term reliability COMPLIANT HALOGEN
- Halogen-free according to IEC 61249-2-21 definition
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-50WQ10FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

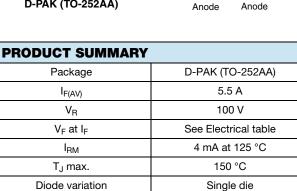
MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	5.5	А						
V _{RRM}		100	V						
I _{FSM}	t _p = 5 μs sine	330	A						
V _F	5 Apk, T _J = 125 °C	0.63	V						
TJ	Range	- 40 to 150	C°						

VOLTAGE RATINGS									
PARAMETER SYMBOL VS-50WQ10FN-M3 UNITS									
Maximum DC reverse voltage	V _R	100	N/						
Maximum working peak reverse voltage	V _{RWM}	100	V						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C	5.5					
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	330	А			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	110				
Non-repetitive avalanche energy	E _{AS}	$T_{J} = 25 \text{ °C}, I_{AS} = 0.5 \text{ A}, L = 40 \text{ n}$	6.0	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	0.5	А				



 E_{AS}



Q 4, 2

Single die

6 mJ

ÓЗ





FREE

VS-50WQ10FN-M3

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
		5 A	T.I = 25 °C	0.77	V				
Maximum forward voltage drop	V (1)	10 A	1j=25 C	0.91					
See fig. 1	V _{FM} ⁽¹⁾	5 A	T.I = 125 °C	0.63					
		10 A	$I_{\rm J} = 125$ C	0.74					
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	1	mA				
See fig. 2	IRM \''	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	4					
Threshold voltage	V _{F(TO)}	- T _J =T _J maximum -		0.47	V				
Forward slope resistance	r _t			21.46	mΩ				
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	183	pF					
Typical series inductance	L _S	Measured lead to lead 5 mm	5.0	nH					

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W					
Approvimeto weight			0.3	g					
Approximate weight			0.01	oz.					
Marking device		Case style D-PAK (similar to TO-252AA)	50WQ10FN						

Note

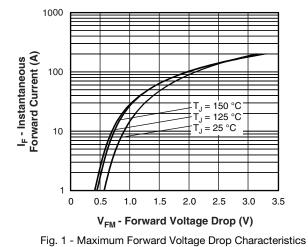
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

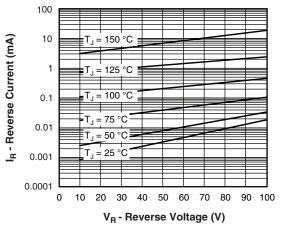


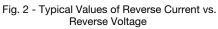
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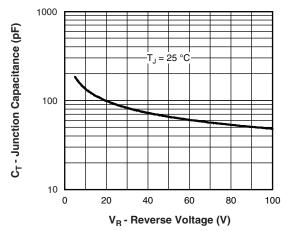


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

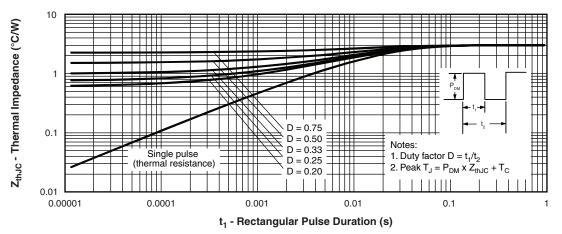


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

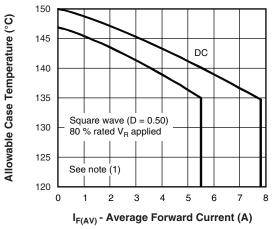
VS-50WQ10FN-M3

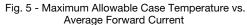
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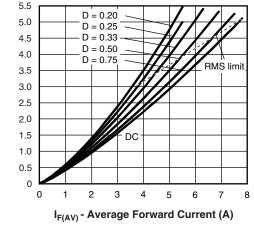
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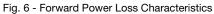
Average Power Loss (W)

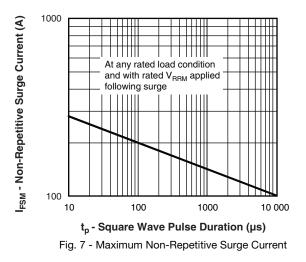












Note

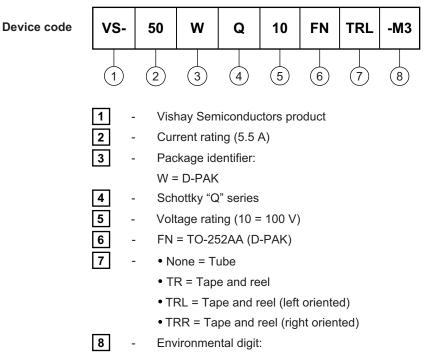
⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R



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ORDERING INFORMATION TABLE



-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-50WQ10FN-M3	75	3000	Antistatic plastic tube						
VS-50WQ10FNTR-M3	2000	2000	13" diameter reel						
VS-50WQ10FNTRL-M3	3000	3000	13" diameter reel						
VS-50WQ10FNTRR-M3	3000	3000	13" diameter reel						

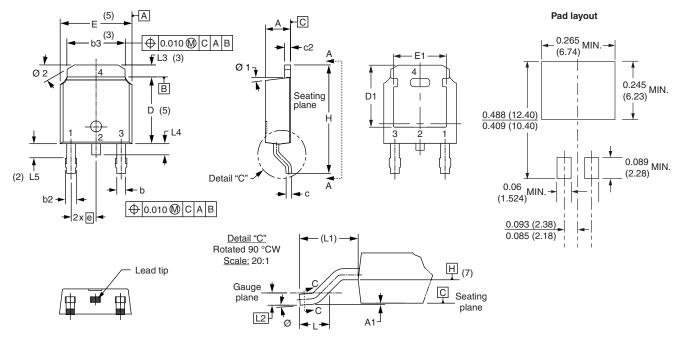
LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					



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D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES			SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

Document Number: 95016



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